STEALTH[™] Rectifier 30 A, 600 V

ISL9R3060G2-F085

Description

The ISL9R3060G2–F085 is STEALTH diode optimized for low loss performance in high frequency hard switched applications. The STEALTH family exhibits low reverse recovery current (I_{RRM}) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RRM} and short t_a phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Features

- High Speed Switching ($t_{rr} = 31 \text{ ns(Typ.)}$ @ $I_F = 30 \text{ A}$)
- Low Forward Voltage ($V_F = 2.4 \text{ V(Max.)} @ I_F = 30 \text{ A}$)
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

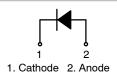
Applications

- Automotive DCDC converter
- Automotive On Board Charger
- Switching Power Supply
- Power Switching Circuits



ON Semiconductor®

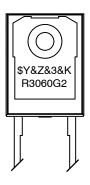
www.onsemi.com





TO-247-2LD CASE 340CL

MARKING DIAGRAM



- \$Y = ON Semiconductor Logo &Z = Assembly Plant Code
- &3 = Date Code (Year & Week) &K = Lot Traceability Code
- R3060G2 = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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ABSOLUTE MAXIMUM RATINGS $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
Vrrm	Peak Repetitive Reverse Voltage	600	V
Vrwм	Working Peak Reverse Voltage	600	V
V _R	DC Blocking Voltage	600	V
lF(AV)	Average Rectified Forward Current @ T _C = 125°C	30	Α
IFSM	Non-repetitive Peak Surge Current (Halfwave 1 Phase 60 Hz)	325	Α
Eavl	Avalanche Energy (1 A, 40 mH)	20	mJ
TJ, TSTG	Operating Junction and Storage Temperature	-55 to +175	°C

THERMAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max	Units
Rелс	Maximum Thermal Resistance, Junction to Case	0.58	°C/W
Reja	Maximum Thermal Resistance, Junction to Ambient	45	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Tube	Quantity
R3060G2	ISL9R3060G2-F085	TO-247	-	30

ELECTRICAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Conditions		Min.	Тур.	Max	Units
I _R	Instantaneous Reverse Current	V _R = 600 V	T _C = 25°C	-	-	100	μΑ
			T _C = 175°C	-	-	2	mA
V _{FM} ¹	Instantaneous Forward Voltage	I _F = 30 A	T _C = 25°C	-	2.0	2.4	V
			T _C = 175°C	-	1.5	2.2	V
t _{rr} ²	Reverse Recovery Time	I_F = 1 A, di/dt = 200 A/ μ s, V_{CC} = 390 V	T _C = 25°C	-	23	35	ns
		$I_F = 30 \text{ A, di/dt} = 200 \text{ A/}\mu\text{s,} \ V_{CC} = 390 \text{ V}$	T _C = 25°C T _C = 175°C	-	31 135	45 -	ns ns
t _a t _b Q _{rr}	Reverse Recovery Time Reverse Recovery Charge	$I_F = 30 \text{ A, di/dt} = 200 \text{ A/}\mu\text{s,}$ $V_{CC} = 390 \text{ V}$	T _C = 25°C	- - -	18 13 48		ns ns nC
E _{AVL}	Avalanche Energy	I _{AV} =1.0 A, L = 40 mH		20	_	_	mJ

^{1.} Pulse: Test Pulse width = 300 μ s, Duty Cycle = 2%.

^{2.} Guaranteed by design.

TEST CIRCUIT WAVEFORMS

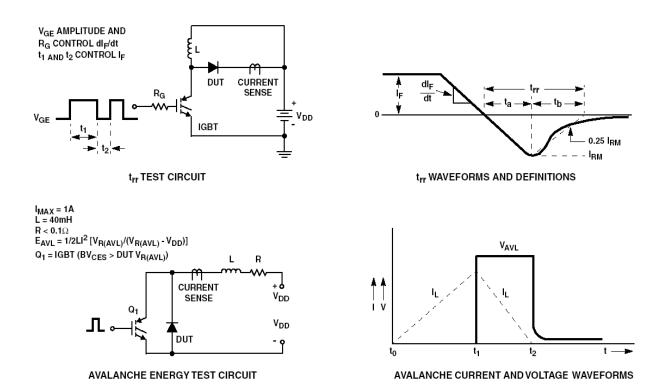


Figure 1. Test Circuit Waveforms

TYPICAL PERFORMANCE CHARACTERISTICS

Reverse Current , IR [µA]

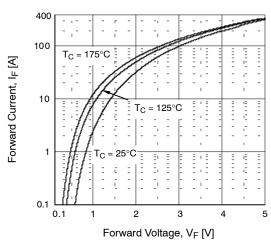


Figure 2. Typical Forward Voltage Drop vs. Forward Current

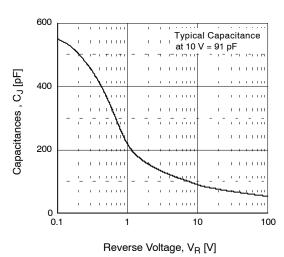


Figure 4. Typical Junction Capacitance

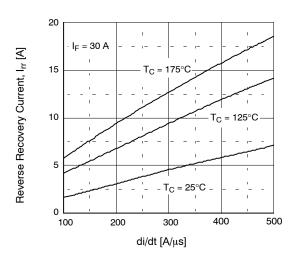


Figure 6. Typical Reverse Recovery Current vs. di/dt

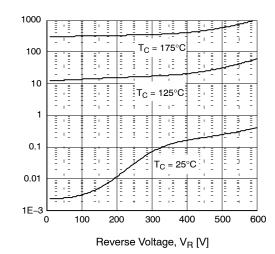


Figure 3. Typical Reverse Current vs. Reverse Voltage

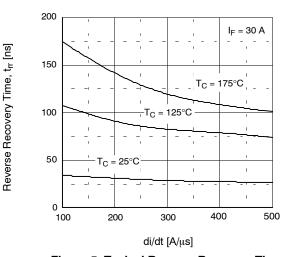


Figure 5. Typical Reverse Recovery Time vs. di/dt

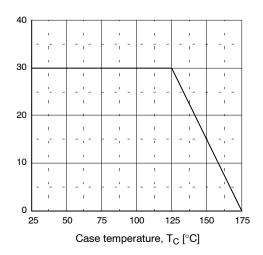


Figure 7. Forward Current Derating Curve

Average Forward Current, IF(AV) [A]

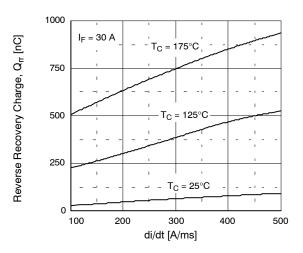


Figure 8. Reverse Recovery Charge

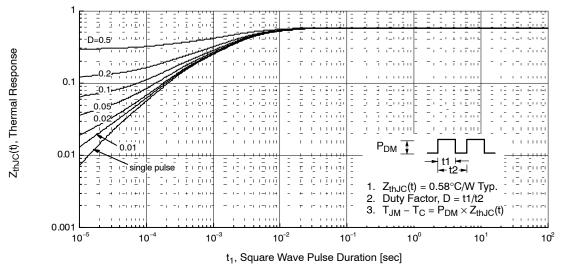
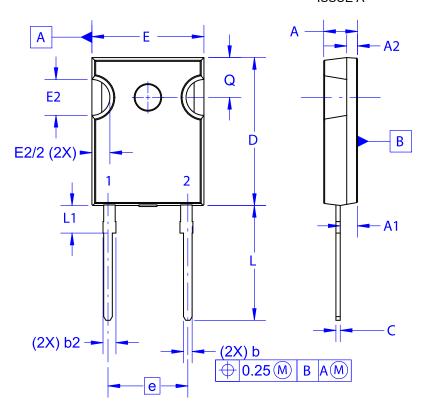


Figure 9. Transient Thermal Response Curve

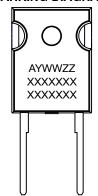
TO-247-2LD CASE 340CL **ISSUE A**





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
 D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

= Assembly Location

= Year

WW = Work Week

= Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

	DATE 03 E	
Ø P —		Ø P1 D2
E1 —	1	D1
,		9

DIM	MIL	LIMETER	S
	MIN	NOM	MAX
Α	4.58	4.70	4.82
A1	2.29	2.40	2.66
A2	1.30	1.50	1.70
b	1.17	1.26	1.35
b2	1.53	1.65	1.77
С	0.51	0.61	0.71
D	20.32	20.57	20.82
D1	16.37	16.57	16.77
D2	0.51	0.93	1.35
Е	15.37	15.62	15.87
E1	12.81	~	~
E2	4.96	5.08	5.20
е	~	11.12	~
L	15.75	16.00	16.25
L1	3.69	3.81	3.93
ØΡ	3.51	3.58	3.65
ØP1	6.61	6.73	6.85
Q	5.34	5.46	5.58
S	5.34	5.46	5.58

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DESCRIPTION:	TO-247-2LD		PAGE 1 OF 1	

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